

PBHV3160ZX Datasheet

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DiGi Electronics Part Number PBHV3160ZX-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number PBHV3160ZX

Description TRANS PNP 600V 0.1A SOT223

Detailed Description Bipolar (BJT) Transistor PNP 600 V 100 mA 38MHz 6

50 mW Surface Mount SOT-223



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
Manufacturer Product Number.	Manufacturer.
PBHV3160ZX	Nexperia USA Inc.
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
PNP	100 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
600 V	250mV @ 6mA, 30mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
100nA	70 @ 10mA, 10V
Power - Max:	Frequency - Transition:
650 mW	38MHz
Operating Temperature:	Grade:
150°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q100	Surface Mount
Package / Case:	Supplier Device Package:
TO-261-4, TO-261AA	SOT-223
Base Product Number:	
PBHV3160	

Environmental & Export classification

8541.21.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	

1. General description

PNP high-voltage low V_{CEsat} transistor in a medium power SOT223 (SC-73) Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- High voltage
- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C
- High collector current gain h_{FE} at high I_C

3. Applications

- Electronic ballast for fluorescent lighting
- LED driver for LED chain module
- LCD backlighting
- · Hook switch for wired telecom
- Switch Mode Power Supply (SMPS)

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	-600	V
I _C	collector current		-	-	-0.1	Α
h _{FE}	DC current gain	$V_{CE} = -10 \text{ V}; I_{C} = -10 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$	70	130	-	

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	4	C
2	С	collector		в
3	Е	emitter		
4	С	collector	∃1 ∃2 ∃3	Ė
			SC-73 (SOT223)	sym028



600 V, 0.1 A PNP high-voltage low VCEsat transistor

6. Ordering information

Table 3. Ordering information

Type number	Package	ckage						
	Name	Description	Version					
PBHV3160Z		plastic, surface-mounted package with increased heatsink; 4 leads; 2.3 mm pitch; 6.5 mm x 3.5 mm x 1.65 mm body	SOT223					

7. Marking

Table 4. Marking codes

Type number	Marking code
PBHV3160Z	HV316Z

8. Limiting values

Table 5. Limiting values

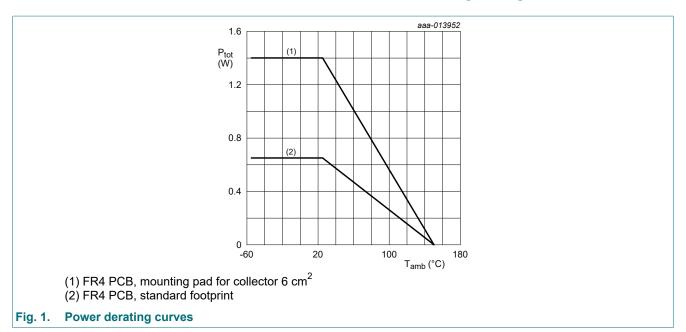
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	-600	V
V_{CEO}	collector-emitter voltage	open base		-	-600	V
V _{CESM}	collector-emitter peak voltage	V _{BE} = 0 V		-	-600	V
V _{EBO}	emitter-base voltage	open collector		-	-6	V
Ic	collector current			-	-0.1	Α
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	0.65	W
			[2]	-	1.4	W
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

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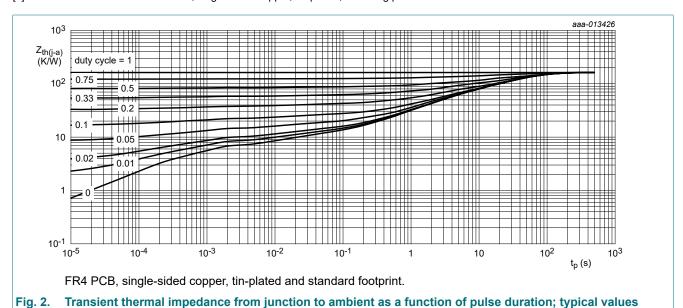


9. Thermal characteristics

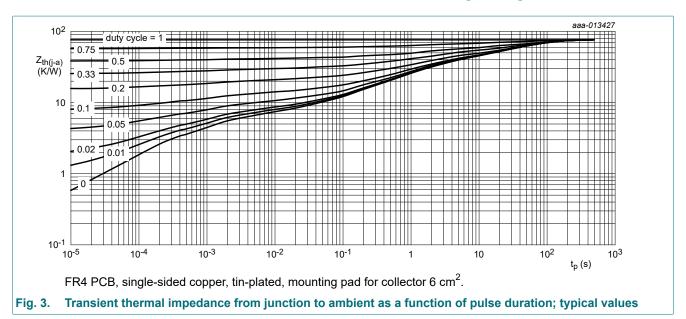
Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air	[1]	-	-	190	K/W
	junction to ambient		[2]	-	-	89	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	-	20	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².



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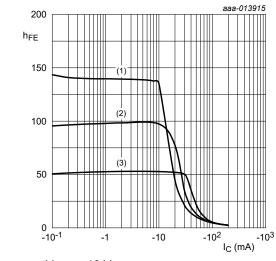


10. Characteristics

Table 7. Characteristics

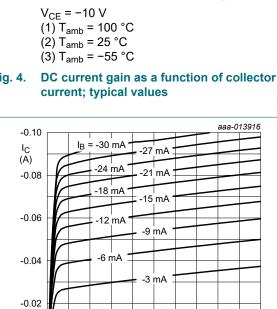
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V _{CB} = -400 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-100	nA
	current	V _{CB} = -400 V; I _E = 0 A; T _j = 150 °C	-	-	-10	μΑ
I _{CES}	collector-emitter cut-off current	$V_{CE} = -400 \text{ V}; V_{BE} = 0 \text{ V}; T_{amb} = 25 \text{ °C}$	-	-	-100	nA
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C	-	-	-100	nA
h _{FE}	DC current gain	V_{CE} = -10 V; I_{C} = -10 mA; T_{amb} = 25 °C	70	130	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -30 \text{ mA}; I_B = -6 \text{ mA}; T_{amb} = 25 \text{ °C}$	-	-150	-250	mV
V _{BEsat}	base-emitter saturation voltage	I_C = -50 mA; I_B = -5 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	-950	mV
f _T	transition frequency	V _{CE} = -10 V; I _C = -5 mA; f = 100 MHz	-	38	-	MHz
C _c	collector capacitance	V_{CB} = -20 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C	-	6	-	pF
C _e	emitter capacitance	V_{EB} = -0.5 V; I_{C} = 0 A; i_{c} = 0 A; f = 1 MHz; T_{amb} = 25 °C	-	76	-	pF

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$$V_{CE} = -10 \text{ V}$$

Fig. 4. current; typical values



 T_{amb} = 25 °C

-1

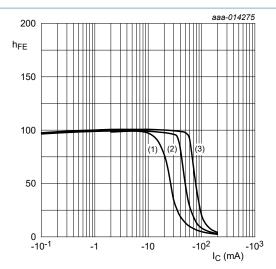
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Fig. 6. Collector current as a function of collectoremitter voltage; typical values

-2

-3

-4 V_{CE} (V)



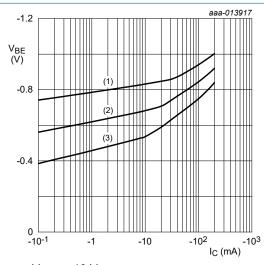
 $h_{FE} = f_{(IC)}$ $T_{amb} = 25 \,^{\circ}C$ (1) $V_{CE} = -10 \,^{\circ}V$

$$T_{amb} = 25 \,^{\circ}C$$

(2)
$$V_{CE} = -25 \text{ V}$$

(3) $V_{CE} = -50 \text{ V}$

DC current gain as a function of collector Fig. 5. current; typical values



 $V_{CE} = -10 \text{ V}$

$$(1) T_{amb} = -55 °C$$

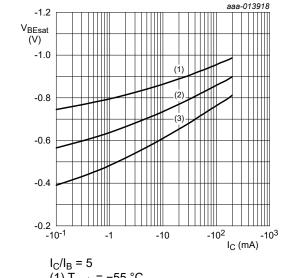
(2) $T_{amb} = 25 \, ^{\circ}C$

(3) $T_{amb} = 100 \, ^{\circ}C$

Fig. 7. Base-emitter voltage as a function of collector current; typical values

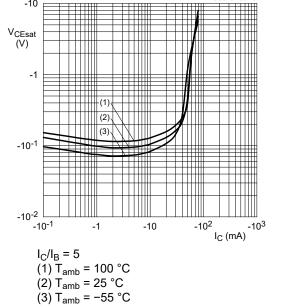
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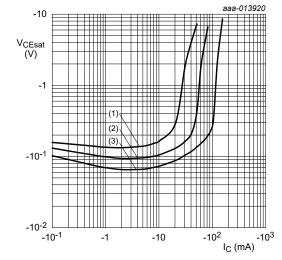


(1) $T_{amb} = -55 \,^{\circ}\text{C}$ (2) $T_{amb} = 25 \,^{\circ}\text{C}$ (3) $T_{amb} = 100 \,^{\circ}\text{C}$

Fig. 8. Base-emitter saturation voltage as a function of Fig. 9. collector current; typical values



Collector-emitter saturation voltage as a function of collector current; typical values

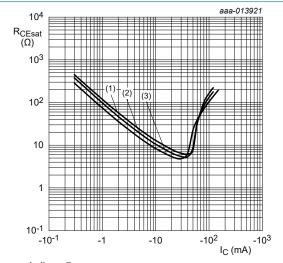


 T_{amb} = 25 °C

(1) $I_C/I_B = 10.0$ (2) $I_C/I_B = 5.0$

 $(3) I_{\rm C}/I_{\rm B} = 2.5$

Fig. 10. Collector-emitter saturation voltage as a function of collector current; typical values



 $I_C/I_B = 5$

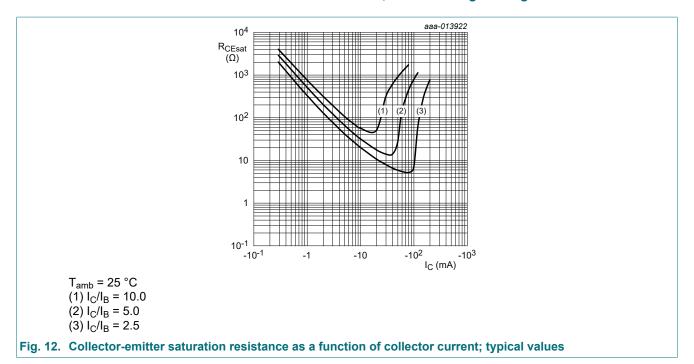
(1) T_{amb} = 100 °C

(2) T_{amb} = 25 °C

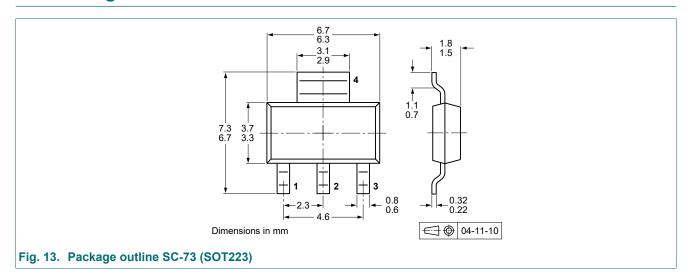
(3) $T_{amb} = -55 \, ^{\circ}C$

Fig. 11. Collector-emitter saturation resistance as a function of collector current; typical values

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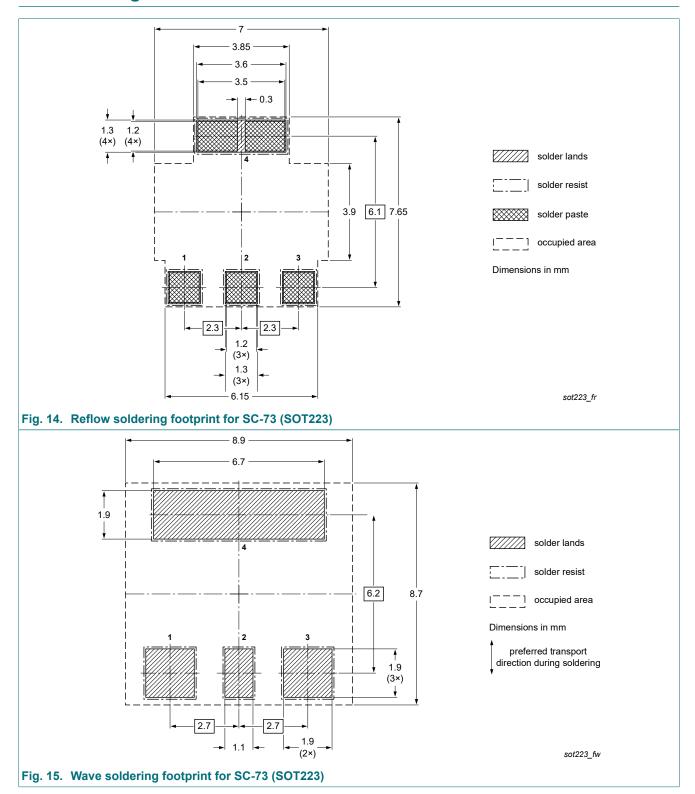
11. Package outline



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12. Soldering



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13. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes				
PBHV3160Z v.2	20241009	Product data sheet	-	PBHV3160Z v.1				
Modifications:	Product(s) changed to non-automotive qualification. Please refer to nexperia.com for automotive (-Q) product alternative(s).							
PBHV3160Z v.1	20140818	Product data sheet	-	-				

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14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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